

	Type	L #	Hits	Search Text	DBs	Time Stamp	C o m m e n t s	E r r o r D e f i n i t i o n	E r r o r s
1	BRS	L1	0	(clean\$3 or etch\$3) same semicondcutor same (oxoethylene or oxypropylene)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 15:11			0
2	BRS	L8	170	(clean\$3 or etch\$3) same (oxoethylene or oxypropylene)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 17:58			0
3	BRS	L15	0	8 and "19991004"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 11:18			0
4	BRS	L22	136	8 and @pd<=19991004	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 13:22			0
5	BRS	L29	2	(clean\$3 or etch\$3) same (oxoethylene or oxypropylene) same (H2O or water) same ((TMAH or "tetramethyl ammonium" or sodium or potassium or ammonium) adj hydroxide))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 13:08			0
6	BRS	L36	0	(clean\$3 or etch\$3) same (oxoethylene or oxypropylene) same (H2O or water) same ((TMAH or "tetramethyl ammonium" or sodium or potassium or ammonium) adj hydroxide)) same ("hydrogen peroxide" or H2O2 or peroxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 13:09			0
7	BRS	L43	225	(clean\$3 or etch\$3) and (oxoethylene or oxypropylene) and (H2O or water) and ((TMAH or "tetramethyl ammonium" or sodium or potassium or ammonium) adj hydroxide)) and ("hydrogen peroxide" or H2O2 or peroxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 13:25			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	C o m m e n t s	E r r o r D e f i n i t i o n	E r r o r s
8	BRS	L50	7	43 and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 13:11			0
9	BRS	L57	165	43 and @pd<=19991004	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 14:29			0
10	BRS	L64	4	(clean\$3 or etch\$3) same (oxoethylene or oxypropylene) same ("hydrogen peroxide" or H2O2 or peroxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 13:27			0
11	BRS	L71	461	(clean\$3 or etch\$3) and (oxoethylene or oxypropylene) and ("hydrogen peroxide" or H2O2 or peroxide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 13:28			0
12	BRS	L92	331	71 and @pd<=19991004	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 14:37			0
13	BRS	L99	0	92 and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:36			0
14	BRS	L106	17	92 and 134/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:45			0
15	BRS	L113	1	92 and 216/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:47			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	C o m m e n t s	E r r o r D e f i n i t i o n	E r r o r s
16	BRS	L120	38	92 and 252/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:51			0
17	BRS	L127	17	106 and @pd<=19991004	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 14:38			0
18	BRS	L134	1	113 and @pd<=19991004	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:30			0
19	BRS	L141	38	120 and @pd<=19991004	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 14:40			0
20	BRS	L148	97	(clean\$3 or etch\$3) same (composition or pH or component or concentration) same (variable or parameter) same semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:12			0
21	BRS	L155	721	(clean\$3 or etch\$3) same (composition or pH or component) same (variable or parameter or vary\$3 or chang\$3 or alter\$6) same semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:16			0
22	BRS	L162	123 3	(clean\$3 or etch\$3) same (composition or pH or component or mole) same (variable or parameter or vary\$3 or chang\$3 or alter\$6) same semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:31			0
23	BRS	L169	796	162 and @pd<=19991004	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:33			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	C o m m e n t s	E r r o r D e f i n i t i o n	E r r o r s
24	BRS	L176	623	(clean\$3 or etch\$3) same (component or mole) same (variable or parameter or vary\$3 or chang\$3 or alter\$6) same semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:33			0
25	BRS	L183	370	176 and @pd<=19991004	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:33			0
26	BRS	L190	3	183 and 438/745	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:35			0
27	BRS	L197	106	183 and 438/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:36			0
28	BRS	L204	10	183 and 134/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:45			0
29	BRS	L211	36	183 and 216/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:48			0
30	BRS	L218	264	183 not 197	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:49			0
31	BRS	L225	13	211 not 197	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 16:49			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	C o m m e n t s	E r r o r D e f i n i t i o n	E r r o r s
32	BRS	L232	11	183 and 252/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/06/01 17:00			0